

MPD Cport MPSE Current Limit and dV/dt

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TBDs in Draft 1.3

Table 169–5—PSE output requirements

	Item	Parameter	Symbol	Unit	Min	Max	Туре	Additional Information
ſ	1	DC output voltage	V _{MPSE(PON)}	V	26	30	0	
		POWER_ON state			45	50	1	
	2	Continuous output	P _{MPSE}	W	26	100	0	
		POWER_ON state			45	100	1	
	Э	Output slew rate		dV/dt	TBD	TBD	ALL	
	4	Output current - at short circuit condi- tion	I _{LIM}	A	TBD	TBD	ALL	
	5	Short-circuit time limit	T _{LIM}	ms	10	75	ALL	
	6	Inrush time	T _{Inrush}	ms	10	20	ALL	
	7	MPD maintain power signature dropout time limit	T _{TPSDO}	ms	320	400	ALL	
	8	PD TPS time for validity	T _{TPS}	ms	6	-	ALL	
	9	DC TPS current	I _{HOLD}	Α	4	9	ALL	
	10	Error delay timing	T _{ED}	ms	750	-	ALL	
	11	Overload current	I _{CUT}	A	P _{MPSE} /V _{MPS} E(PON)	-	ALL	
	12	Overload time limit	T _{CUT}	ms	50	70	ALL	

Table 169–8—MPD power supply limits

Item	Parameter	Symbol	Unit	Min	Max	Туре	Additional Information
1	Input voltage	VPort_MPD	V	16	30	0	
				34	50	1	
2	Unit power	P _{MPD_1U}	W		1	0	1 unit load
					2	1	1 unit load
3	Unit loading	N _{unit}	-	1	16	ALL	Must be an inte- ger
4	Input power	P _{MPD}	W	1	16	0	N _{unit} *
				2	32	1	P _{MPD_1U}
5	Inrush current	I _{Inrush_MPD}	А	-	.01	ALL	
6	MPD Type 0 Voltage threshold	V _{type0_th}	V	11.9	16	ALL	
7	MPD Type 1 Voltage threshold	V _{type1_th}	V	30.1	34	ALL	
8	Inrush backoff time	T _{Inrush} backo ff	ms	10	20	ALL	
9	Inrush to operating state delay	T _{Delay}	ms	10	20	ALL	
10	MPD MPI capaci- tance during POWER_ON	C _{Port}	μF	-	TBD	ALL	>
11	MPD current when connected to in- compatible MPSE type	I _{MPD_} Disable d	μА	-	500	ALL	



MPSE Current Limit and MPD Cport Requirements

MPSEs need to protect their power path during shorting events, while allowing some margin for over current events in a normally operating system.

MPDs need local bulk capacitance to provide a short loop path for local switching currents and filter load transients.

For example:

- Addition of a node to an already operating system
- MPSE Supply Voltage Step
- Common mode voltage shift
- Etc..

MPSE Current limit must provide current to MPDs and extra charge to MPD bulk caps during a load step

For example:

Prevent high frequency edges from conducting on the mixing segment

Charge reservoir to operate through common mode surge



llimit, Cport, and Mixing Segment dV/dt

- Simple phy input model has a wide bandwidth high pass filter
- Power system dV/dt is affected by Cport and Ilimit
 - Higher Cport leads to lower dV/dt
 - Lower current limit leads to lower dV/dt



Load Step Simulations



Method

Variables:

- Cport = 10uF, 180uF
- Mixing segment length = 1m, 50m

Step 16 MPD loads from 0W to 1W (16W total) Look for effects on transceiver input voltage: "VMPD16:PHY" V MPD16:PHY = V(XCV+,XCV-) on node 16





Load Step 1

Nodes = 16

Step loads from 0 -> 1W simultaneously

50 meter mixing segment

Cport = 180uF

~100mV glitch on transceiver input





Load Step 2

Nodes = 16

Step loads from 0 -> 1W simultaneously

50 meter mixing segment

Cport = 10uF

~800mV glitch on transceiver input



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Variable Loading

16 MPDs changing between 0W -> 1W -> 0W at different times

Each MPD has 10uF Cport

Expect baseline noise at transceiver input



Supply Step Simulations



Method

Variables:

- Ilim = 1.1A, 3.8A
- Cport = 10uF, 180uF
- Mixing segment length = 1m, 50m

Step MPSE supply from 21.5V to 26.4V Look for effects on transceiver input voltage: "VMPD16:PHY" V MPD16:PHY = V(XCV+,XCV-) on node 16





Step MPSE Voltage from 21.5V to 26.4V

50 meter mixing segment

llim = 1.1A

Nodes = 16

MPDs sinking 1W each

Cport = 180uF

Tlim < 50ms



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Step MPSE Voltage from 21.5V to 26.4V

50 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 100W / 26.4V = 3.8A

Cport = 180uF

Tlim < 1ms







Step MPSE Voltage from 21.5V to 26.4V

50 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 3.8A

Cport = 10uF

Tlim < 1ms

Bold Lines highlight parameter change from last slide





Step MPSE Voltage from 21.5V to 26.4V

50 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 1.1A

Cport = 10uF

Tlim < 1ms

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Step MPSE Voltage from 21.5V to 26.4V

1 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 1.1A

Cport = 10uF

Tlim < 1ms

Bold Lines highlight parameter change from last slide



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Step MPSE Voltage from 21.5V to 26.4V

1 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 3.8A

Cport = 10uF

Tlim < N/A

Bold Lines highlight parameter change from last slide





Step MPSE Voltage from 21.5V to 26.4V

1 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 3.8A

Cport = 180uF

Tlim < 1ms

Bold Lines highlight parameter change from last slide



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Step MPSE Voltage from 21.5V to 26.4V

1 meter mixing segment

Nodes = 16

MPDs sinking 1W each

llim = 1.1A

Cport = 180uF

Tlim < 1ms

Bold Lines highlight parameter change from last slide







Summary

Length	llim	Cport	Vmax,phy
50	1.1	180	0.05
50	3.8	180	0.14
50	3.8	10	1.5
50	1.1	10	0.9
1	1.1	10	1.6
1	3.8	10	2.8
1	3.8	180	0.35
1	1.1	180	0.05

Smallest excursions are with:

- Large Cport
- Low Ilim



Suggested Current / Cport Limits

Current Limit

1.10A min

1.25A typ.

1.40A max

Attempt to provide at least 1.10A before current limit Typical value of 1.25A +/- 12%

Cport max

Set to 180uF - Same as PoE

1.1A can inrush 16 nodes with 180uF Cport capacitance drawing full load (1W) each

Limit time is 48ms

Suggest we increase Tlim,min to 50ms Maintain 75ms Tlim,max



Resolution to comments 102, 103 and 104

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4	Output current - at	I _{LIM}	Α		-TBD-	ALL	
	short circuit condi- tion			1.1	1.4		
5	Short-circuit time limit	T _{LIM}	ms	50	75	ALL	
6	Inrush time	T _{Inrush}	ms	10	20	ALL	
7	MPD maintain power signature dropout time limit	T _{TPSDO}	ms	320	400	ALL	
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10	MPD MPI capaci- tance during POWER_ON	C _{Port}	μF	-	твр 180	ALL	
11	MPD current when connected to in- compatible MPSE type	I _{MPD_Disable} d	μΑ	-	500	ALL	



Thank You